

Fixed Frequency PWM Controller - in DSO-8 Package

Product highlights

- Enhanced Active Burst Mode with selectable entry and exit standby power to reach the lowest standby power <100 mW
- Digital frequency reduction for better overall system efficiency
- Fast startup achieved with cascode configuration
- Frequency jitter and soft gate driving for low EMI
- Integrated error amplifier
- Comprehensive protection with input line over voltage protection
- Pb-free lead plating, halogen-free mold compound, RoHS compliant

Features

- Enhanced Active Burst Mode with selectable entry and exit standby power
- Digital frequency reduction for better overall system efficiency
- Fast startup achieved with cascode configuration
- DCM and CCM operation with slope compensation
- Frequency jitter and soft gate driving for low EMI
- Built-in digital soft start
- Integrated error amplifier to support direct feedback in non-isolated flyback
- Comprehensive protection with input line over voltage protection, V_{cc} over voltage, V_{cc} under voltage, overload/open loop, over temperature and Current Sense (CS) short to GND
- All protections are in auto restart mode
- Limited charging current for V_{cc} short to GND

Applications

- Auxiliary power supply for home appliances/white goods, TV, PC & server
- Blu-ray player, set-top box & LCD/LED monitor

Product validation

Fully qualified according to JEDEC for Industrial Applications

Description

The ICE5xSAG is the $5th$ generation of fixed frequency PWM controller optimized for off-line switch mode power supply in cascode configuration. The cascode configuration helps achieve fast startup. The frequency reduction with soft gate driving and frequency jitter operation offers lower EMI and better efficiency between light load and 50% load. The selectable entry and exit standby power ABM enables flexibility and ultra-low power consumption at standby mode with small and controllable output voltage ripple. The product has a wide operating range $(10.0 \times 25.5 \text{ V})$ of IC power supply and lower power consumption. The numerous protection functions with adjustable line over voltage protection support the power supply system in failure situations. All these make the $5th$ generation ICE5xSAG series an outstanding PWM controller for fixed frequency flyback converter in the market.

Figure 1 Typical application in isolated flyback using TL431 and optocoupler

Output power of 5th generation Fixed-Frequency PWM controller

Table 1 Output power of $5th$ generation Fixed-Frequency PWM controller

 \overline{a}

 1 Calculated maximum output power rating in an open frame design at T $_{\rm a}$ =50 °C, T $_{\rm J}$ =125 °C using minimum pin copper area in a 2 oz copper single sided PCB. The output power figure is for selection purpose only. The actual power can vary depending on particular designs. Please contact to a technical expert from Infineon for more information.

Pin configuration and functionality

Table of contents

Pin configuration and functionality

Pin configuration and functionality

1 Pin configuration and functionality

The pin configuration is shown i[n Figure 3](#page-4-1) and the functions are described i[n Table 2.](#page-4-2)

Figure 3 Pin configuration

Table 2 Pin definitions and functions

Representative block diagram

2 Representative block diagram

Figure 4 Representative block diagram

3 Functional description

3.1 V_{CC} pre-charging and typical V_{CC} voltage during start-up

As shown in [Figure 1,](#page-1-1) once the line input voltage is applied, a rectified voltage appears across the capacitor C_{bus} . The pull up resistor R_{STARTUP} provides a current to charge the C_{iss} (input capacitance) of power MOSFET and gradually generate one voltage level. If the voltage over C_{iss} is high enough, power MOSFET turns on and V_{CC} capacitor will be charged through primary inductance of transformer L_{P} , power MOSFET and internal diode D_1 with two steps constant current source $I_{\text{VCC_Charged}}^1$ and $I_{\text{VCC_Charged}}^1$.

A very small constant current source ($I_{VCC_charge1}$) is charged to the V_{CC} capacitor till V_{CC} reach V_{CC_SCP} to protect the controller from V_{cc} pin short to ground during the start up. After this, the second step constant current source ($I_{VCC_Charge3}$) is provided to charge the V_{CC} capacitor further, until the V_{CC} voltage exceeds the turned-on threshold V_{VCC_ON} . As shown in the time phase I i[n Figure 5,](#page-6-2) the V_{CC} voltage increase almost linearly with two steps.

Figure 5 V_{cc} voltage and current at startup

The time taking for the V_{cc} pre-charging can then be approximately calculated as:

$$
t_1 = t_A + t_B = \frac{V_{VCC_SCP} \cdot C_{VCC}}{I_{VCC_charge1}} + \frac{(V_{VCC_ON} - V_{VCC_SCP}) \cdot C_{VCC}}{I_{VCC_charge3}}
$$
(1)

When the V_{CC} voltage exceeds the V_{CC} turn on threshold V_{VCC_ON} at time t₁, the IC begins to operate with soft-start. Due to power consumption of the IC and the fact that there is still no energy from the auxiliary winding to charge the V_{cc} capacitor before the output voltage is built up, the V_{cc} voltage drops (Phase II). Once the output voltage rises close to regulation, the auxiliary winding starts to charge the V_{cc} capacitor from the time t₂onward and delivering the l_{vcc_Normal}² to the controller. The V_{cc} then will reach a constant value depending on output load.

 \overline{a}

 1 lvcc_{-Charge1/2/3} is charging current from the controller to VCC capacitor during start up

 2 l_{VCC_Normal} is supply current from VCC capacitor or auxiliary winding to the controller during normal operation

3.2 Soft-start

As shown in [Figure 6,](#page-7-5) the IC begins to operate with a soft-start at time t_{on} . The switching stresses on the power MOSFET, diode and transformer are minimized during soft-start. The soft-start implemented in ICE5xSAG is a digital time-based function. The preset soft-start time is t_{ss} (12 ms) with 4 steps. If not limited by other functions, the peak voltage on CS pin will increase step by step from 0.3 V to V_{CS N} (0.8 V) finally. The normal feedback loop will take over the control when the output voltage reaches its regulated value.

Figure 6 Maximum current sense voltage during soft start

3.3 Normal operation

The PWM controller during normal operation consists of a digital signal processing circuit including regulation control and an analog circuit including a current measurement unit and a comparator. Details about the full operation of the PWM controller in normal operation are illustrated in the following paragraphs.

3.3.1 PWM operation and peak current mode control

3.3.1.1 Switch-on determination

The power MOSFET turn-on is synchronized with the internal oscillator with a switching frequency f_{SW} that corresponds to the voltage level V_{FB} (se[e Figure 8\)](#page-9-2).

3.3.1.2 Switch-off determination

In peak current mode control, the PWM comparator monitors voltage V_1 (se[e Figure 4\)](#page-5-1) which is the representation of the instantaneous current of the power MOSFET. When V_1 exceeds V_{FB} , the PWM comparator sends a signal to switch off the GATE of the power MOSFET. Therefore, the peak current of the power MOSFET is controlled by the feedback voltage V_{FB} (see [Figure 7\)](#page-8-1).

At switch on transient of the power MOSFET, a voltage spike across R_{cs} can cause V₁ to increase and exceed V_{FB}. To avoid a false switch off, the IC has a blanking time $t_{CS|LEB}$ before detecting the voltage across R_{CS} to mask the voltage spike. Therefore, the minimum turn on time of the power MOSFET is $t_{CS_{\text{LEB}}}$.

For some reason that the voltage level at V₁ takes long time to exceed V_{FB}, the IC has implemented a maximum duty cycle control to force the power MOSFET to switch off when $D_{MAX} = 0.75$ is reached.

Figure 7 Pulse width modulation

3.3.2 Current sense

The power MOSFET current generates a voltage V_{CS} across the current sense resistor R_{CS} connected between the CS pin and the GND pin. V_{cs} is amplified with gain G_{PWM}, then, added with an offset V_{PWM} to become V₁ as described below in below equation 3.

- G_{PWM} : PWM-OP gain
- V_{PWM} : offset for voltage ramp

3.3.3 Frequency reduction

Frequency reduction is implemented in ICE5xSAG to achieve a better efficiency during the light load. At light load, the reduced switching frequency F_{SW} improves efficiency by reducing the switching loses.

When load decreases, V_{FB} decreases as well. F_{sw} is dependent on the V_{FB} as shown i[n Figure 8.](#page-9-2) Therefore, F_{sw} decreases as the load decreases.

Typically, F_{sw} at high load is 100 kHz/ 125 kHz and starts to decrease at V_{FB} = 1.7V. There is no further frequency reduction once it reached the $f_{\text{OSCx MIN}}$ even the load is further reduced.

Figure 8 Frequency reduction curve

3.3.4 Slope compensation

ICE5xSAG can operate at Continuous Conduction Mode (CCM). At CCM operation, duty cycle greater than 50% may generate a sub-harmonic oscillation. To avoid the sub-harmonic oscillation, slope compensation is added to V_{cs} pin when the gate of the power MOSFET is turned on for more than 40% of the switching cycle period. The relationship between V_{FB} and the V_{CS} for CCM operation is described in below equation 4:

 $V_{FB} = V_{CS} * G_{\text{PWM}} + V_{\text{PWM}} + M_{\text{COMP}} * (T_{\text{ON}} - 40\% * T_{\text{PERIOD}})$ (4)

where, T_{ON} : gate turn on time of the power MOSFET

M_{COMP} : slope compensation rate

TPERIOD : switching cycle period

Slope compensation circuit is disabled and no slope compensation is added into the V_{CS} pin during active burst mode to save the power consumption.

3.3.5 Oscillator and frequency jittering

The oscillator generates a frequency of 100 kHz/ 125 kHz with frequency jittering of ±4% at a jittering period of T_{JITTER} (4 ms). The frequency jittering helps to reduce conducted EMI.

A capacitor, a current source and current sink which determine the frequency are integrated. The charging and discharging current of the implemented oscillator capacitor are internally trimmed in order to achieve a highly accurate switching frequency.

Once the soft-start period is over and when the IC goes into normal operating mode, the frequency jittering is enabled. There is also frequency jittering during frequency reduction.

3.3.6 Modulated gate drive

The drive-stage is optimized for EMI consideration. The switch on speed is slowed down before it reaches the power MOSFET turn on threshold. That is a slope control of the rising edge at the output of driver (se[e Figure 9\)](#page-10-4). Thus the leading switch spike during turn on is minimized.

Figure 9 Gate rising waveform

3.4 Peak current limitation

There is a cycle by cycle peak current limitation realized by the current limit comparator to provide primary over-current protection. The primary current generates a voltage V_{CS} across the current sense resistor R_{CS} connected between the CS pin and the GND pin. If the voltage V_{CS} exceeds an internal voltage limit $V_{CS,N}$, the comparator immediately turns off the gate drive.

The primary peak current IPEAK_PRI can be calculated as below:

$$
I_{\rm PEAK_PRI} = V_{\rm CS_N}/R_{\rm CS} \tag{5}
$$

To avoid mistriggering caused by MOSFET switch on transient voltage spikes, a leading edge blanking time $(t_{CS,LEB})$ is integrated in the current sensing path.

3.4.1 Propagation delay compensation

In case of overcurrent detection, there is always a propagation delay from sensing the V_{cs} to switching the power MOSFET off. An overshoot on the peak current I_{peak} caused by the delay depends on the ratio of dI/dt of the primary current (se[e Figure 10\)](#page-11-0).

Fixed Frequency PWM Controller - in DSO-8 Package

Functional description

Figure 10 Current limiting

The overshoot of Signal2 is larger than Signal1 due to the steeper rising waveform. This change in the slope is depending on the AC input voltage. Propagation delay compensation is integrated to reduce the overshoot due to dI/dt of the rising primary current. Thus the propagation delay time between exceeding the current sense threshold $V_{CS,N}$ and the switching off of the power MOSFET is compensated over wide bus voltage range. Current limiting becomes more accurate which will result in a minimum difference of overload protection triggering power between low and high AC line input voltage.

Under CCM operation, the same V_{CS} do not result in the same power. In order to achieve a close overload triggering level for CCM, ICE5xSAG has implemented a 2 compensation curve as show[n Figure 11.](#page-11-1) One of the curve is used for T_{ON} greater than 0.40 duty cycle and the other is for lower than 0.40 duty cycle.

Figure 11 Dynamic voltage threshold $V_{CS,N}$

Similarly, the same concept of propagation delay compensation is also implemented in ABM with reduced level. With this implementation, the entry and exit burst mode power can be close between low and high AC line input voltage.

3.5 Active Burst Mode (ABM) with selectable power level

At light load condition, the IC enters ABM operation to minimize the power consumption. Details about ABM operation are explained in the following paragraphs.

3.5.1 Entering ABM operation

The sytem will enter into ABM operation when two conditions below are met:

- the FB voltage is lower than the threshold of $V_{FB-EBLP}/V_{FB-EBHP}$ depending on burst configuration option setup
- and a certain blanking time t_{FB_BEB}

Once all of these conditions are fulfilled, the ABM flip-flop is set and the controller enters ABM operation. This multi-condition determination for entering ABM operation prevents mis-triggering of entering ABM operation, so that the controller enters ABM operation only when the output power is really low.

3.5.2 During ABM operation

After entering ABM, the PWM section will be inactive making the V_{OUT} start todecrease. As the V_{OUT} decreases, V_{FB} rises. Once V_{FB} exceeded V_{FB} $_{\text{BD}}$, the internal circuit is again activated by the internal bias to start with the switching.

If the PWM is still operating and the output load is still low, V_{OUT} increases and V_{FB} signal starts to decrease. When V_{FB} reaches the low threshold V_{FB_BOff} , the internal bias is reset again and the PWM section is disabled with no switching until V_{FB} increases back to exceed V_{FB_0} threshold.

In ABM, V_{FB} is like a sawtooth waveform swinging between V_{FB} Boff and V_{FB} Bon shown i[n Figure 12.](#page-13-0)

During ABM, the switching frequency f_{oscx ABM} is 83 kHz for 100 kHz version and 103 kHz for 125 kHz version IC. The peak current $I_{PEAKABM}$ of the power MOSFET is defined by:

 $I_{\text{PEAK ABM}} = V_{\text{CS BXP}}/R_{\text{CS}}$ (6)

where V_{CS_BxP} is the peak current limitation in ABM

3.5.3 Leaving ABM operation

The FB voltage immediately increases if there is a sudden increase in the output load. When V_{FB} exceeds V_{FB-LB} it will leave ABM and the peak current limitation trhreshold voltage will return back to $V_{CS,N}$ immediately.

Fixed Frequency PWM Controller - in DSO-8 Package

Functional description

Figure 12 Signals in Active Burst Mode

3.5.4 ABM configuration

Table 3 ABM configuration option setup

The burst mode entry level can be selected by changing the different resistance R_{sel} at FB pin. There are 3 configuration options depending on R_{Sel} which corresponds to the options of no ABM (Option 1), low range of ABM power (Option 2) and high range of ABM power (Option 3). The table below shows the control logic for the entry and exit level with the FB voltage.

During IC first startup, the controller preset the ABM selection to Option 3, the FB resistor (R_{FB}) is turned off by internal switch S2 (se[e Figure 13\)](#page-14-2)and a current source Isel is turned on instead.From V_{CC}= 4.44 V to V_{CC} on threshold, the FB pin will start to charge resistor R_{Sel} with current I_{Sel} to a certain voltage level. When V_{cc} reaches V_{cc} on threshold, the FB voltage is sensed. The burst mode option is then chosen according to the FB voltage level. After finishing the selection, any change on the FB level will not change the burst mode option and the current source (I_{sel}) is turned off while the FB resistor (R_{FB}) is connected back to the circuit [\(Figure 13\)](#page-14-2).

Figure 13 ABM detect and adjust

3.6 Non-isolated/isolated configuration

ICE5xSAG has a VERR Pin, which is connected to the input of an integrated error amplifier to support nonisolated flyback application (se[e Figure 2\)](#page-1-2). When V_{cc} is charging and before reaching the V_{cc} on threshold, a current source I_{ERR P} BIAS from VERR pin together with R_{F1} and R_{F2} will generate a voltage across it. If VERR voltage is more than $V_{ERP-BIAS}$ (0.2 V), non-isolated configuration is selected, otherwise, isolated configuration is selected. In isolated configuration, the error amplifier output is disconnected from the FB pin.

In case of non-isolated configuration, the voltage divider R_{F1} and R_{F2} is used to sense the output voltage and compared with the internal reference voltage V_{ERR_REF}. The difference between the sensed voltage and the reference voltage is converted as an output current by the error amplifier. The output current will charge/discharge the resistor and capacitor network connected at the FB pin for the loop compensation.

3.7 Protection functions

The ICE5xSAG provides numerous protection functions which considerably improve the power supply system robustness, safety and reliability. The following table summarizes these protection functions and the corresponding protection mode whether as a non switch auto restart, auto restart or odd skip auto restart mode. Refer t[o Figure 14,](#page-16-3) [Figure 15 a](#page-17-0)n[d Figure 16](#page-17-1) for the waveform illustration of protection modes.

Table 4 Protection functions

3.7.1 Line over voltage

The AC Line Over Voltage Protection (LOVP) is detected by sensing bus capacitor voltage through VIN pin via voltage divider resistors, Rl1 and Rl2 [\(Figure 1\)](#page-1-1). Once V_{VIN} voltage is higher than the line over voltage threshold (V_{VIN_LOVP}), the controller enters into protection mode until V_{VIN} is lower than V_{VIN_LOVP}. This protection can be disabled by connecting VIN pin to GND.

 $3.7.2$ V_{cc} over/under voltage

During operation, the V_{CC} voltage is continuously monitored. If V_{CC} is either below V_{VCC_OFF} for 50 µs (t_{VCC_OFF_B}) or above V_{VCC_OVP} for 55 µs (t_{VCC_OVP_B}), the power MOSFET is kept switch off. After the V_{CC} voltage falls below the threshold V_{VCCoff}, the new start up sequence is activated. The V_{CC} capacitor is then charged up. Once the voltage exceeds the threshold $V_{\text{VCC_ON}}$, the IC begins to operate with a new soft-start.

3.7.3 Overload/ open loop

In case of open control loop or output overload, the FB voltage will be pulled up. When VFB exceeds VFB_OLP after a blanking time of $t_{FB_OLP_B}$, the IC enters odd skip auto restart mode. The blanking time enables the converter to provide a peak power in case the increase in V_{FB} is due to a sudden load increase.

3.7.4 Over temperature

If the junction temperature of controller exceeds T_{jcon_OTP} , the IC enters into Over Temperature Protection (OTP) auto restart mode. The IC has also implemented with a 40 °C hysteresis. That means the IC can only be recovered from OTP when the controller junction temperature is dropped 40 °C lower than the over temperature trigger point.

 \overline{a}

¹ Not Applicable

3.7.5 CS short to GND

If the voltage at the current sense pin is lower than the preset threshold V_{CS_STG} with certain blanking time tcs_sTG_B for three consecutive pulses during on-time of the power switch, the IC enters CS short to GND protection.

 $3.7.6$ V $_{cc}$ short to GND

To limit the power dissipation of the startup circuit at V_{cc} short to GND condition, the V_{cc} charging current is limited to a minimum level of I_{VCC_Charge1}. With such low current, the power loss of the IC is limited to prevent overheating.

3.7.7 Protection modes

All the protections are in auto restart mode with a new soft start sequence. The three auto restart modes are illustrated in the following figures.

Figure 14 Non switch auto restart mode

4 Electrical characteristics

Attention: All voltages are measured with respect to ground (Pin 8). The voltage levels are valid if other ratings are not violated.

4.1 Absolute maximum ratings

Attention: Stresses above the maximum values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit. For the same reason, make sure that any capacitor that will be connected to pin 7 (VCC) is discharged before assembling the application circuit. Ta=25 °C unless otherwise specified.

Parameter **Symbol Limit Values Unit Note / Test Condition** Min. | Max. VCC Supply Voltage V_{CC} $|$ -0.3 $|$ 27.0 $|$ V SOURCE Voltage **V**_{SOURCE} | -0.3 | 27.0 | V GATE Voltage **1988 V**GATE 1 **VGATE** V_{GATE} 1 -0.3 27.0 **V** FB Voltage *V***_{FB}** V_{FB} -0.3 3.6 V VERR Voltage **VERR** Voltage **VERR** 1 -0.3 3.6 V $\begin{array}{c|c|c|c|c|c|c|c|c} \hline \end{array}$ CS Voltage $\begin{array}{c|c|c|c} V_{CS} & -0.3 & 3.6 & V \\ \hline \end{array}$ VIN Voltage **View Contract 2018** V_{IN} | -0.3 | 3.6 | V DC current at SOURCE pin **I** I_{SOURCE} | - | 0.9 | A | Limited by T_{J,Max} Single pulse current at SOURCE pin $I_{S_-\text{pulse}}$ $-$ 5.8 A Pulse width t_p = 20 µs and limited by $T_{J,Max}$ Maximum DC current on any pin \vert 10.0 | 10.0 | mA Except SOURCE and CS pin ESD robustness HBM **VESD HBM** $V_{ESD HBM}$ - 2000 V According to EIA/JESD22 ESD robustness CDM \vert $V_{ESD CDM} \vert$ - \vert 500 V Junction temperature range T_J $\begin{array}{|c|c|c|c|c|c|} \hline 7_J & -40 & 150 & \text{°C} \ \hline \end{array}$ Storage Temperature **1** T_{STORE} -55 150 °C Thermal Resistance (Junction- Ambient) $\begin{vmatrix} R_{\text{thJA}} & | & - \ | & 185 \ | & K/W \ | \end{vmatrix}$ Setup according to the JEDEC standard JESD51

Table 5 Absolute maximum ratings

4.2 Operating range

Note: Within the operating range, the IC operates as described in the functional description.

Table 6 Operating range

4.3 Operating conditions

Note: The electrical characteristics involve the spread of values within the specified supply voltage and junction temperature range TJ from – 40 °C to 125 °C. Typical values represent the median values, which are related to 25 °C. If not otherwise stated, a supply voltage of V_{cc} = 18 V is assumed.

Table 7 Operating conditions

4.4 Internal voltage reference

Table 8 Internal voltage reference

4.5 Gate driver

Table 9 Gate driver

4.6 PWM section

Table 10 PWM section

4.7 Error amplifier

Table 11 Error amplifier

4.8 Current sense

Table 12 Current sense

4.9 Soft start

Table 13 Soft start

4.10 Active Burst Mode

Table 14 Active Burst Mode

Parameter	Symbol	Limit Values				Unit Note / Test Condition
		Min.	Typ.	Max.		
Charging current to select burst mode	I_{sel}	2.5	3.0	3.5	μA	
Burst mode selection reference voltage Threshold	$V_{FB_P_BIAS1}$	1.65	1.73	1.80	V	

¹ The parameter is not subjected to production test - verified by design/characterization

 \overline{a}

Fixed Frequency PWM Controller - in DSO-8 Package

Electrical characteristics

4.11 Line over voltage protection

Table 15 Line OVP

4.12 V_{cc} over voltage protection

Table 16 V_{cc} over voltage protection

4.13 Overload protection

Table 17 Overload protection

4.14 Thermal protection

Table 18 Thermal protection

4.15 CS short to GND protection

Table 19 CS short to GND protection

4.16 Low side MOSFET

Table 20 Low side MOSFET

 \overline{a}

¹The parameter is not subjected to production test - verified by design/characterization

Output power curve

5 Output power curve

The calculated output power curves versus ambient temperature are shown below. The curves are derived based on a typical DCM/CCM flyback in an open frame design setting the maximum T_J at 125 °C, using minimum pin copper area in a 2 oz copper single sided PCB and steady state operation only (no design margins for abnormal operation modes are included).

The output power figure is for reference only. The actual power can vary depending on a particular design. In a power supply system, appropriate thermal design margins must be considered to make sure that the operation of the device is within the maximum ratings given in section 4.1.

Figure 17 Output power curve of ICE5xSAG

Outline dimension

Figure 18 PG-DSO-8

Marking

7 Marking

Figure 19 Marking of PG-DSO-8

Revision history

Revision history

Trademarks

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 Document reference ICE5xSAG

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